BT152B series

GENERAL DESCRIPTION

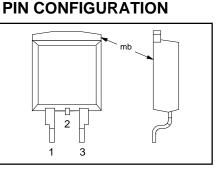
Glass passivated thyristors in a plastic envelope suitable surface for mounting, intended for use in applications requiring high bidirectional voltage blocking capability and high thermal cycling performance. Typical applications include motor control, industrial and domestic lighting, heating and static switching.

QUICK REFERENCE DATA

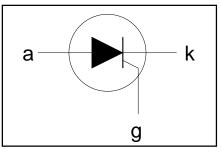
SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V _{DRM} , V	BT152B- Repetitive peak off-state voltages	400R 450	600R 650	800R 800	V
V _{RRM} I _{T(AV)} I _{T(RMS)} I _{TSM}	Average on-state current RMS on-state current Non-repetitive peak on-state current	13 20 200	13 20 200	13 20 200	A A A

PINNING - SOT404

PIN	DESCRIPTION		
1	cathode		
2	anode		
3	gate		
mb	anode		



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MAX.		UNIT
V _{DRM}	Repetitive peak off-state voltages		-	-400R 450 ¹	-600R 650 ¹	-800R 800	V
I _{T(AV)} I _{T(RMS)} I _{TSM}	Average on-state current RMS on-state current Non-repetitive peak on-state current	half sine wave; $T_{mb} \le 103$ °C all conduction angles half sine wave; $T_j = 25$ °C prior to surge	-		13 20		A A
		t = 10 ms t = 8.3 ms	-		200 220		A A
l²t dl _⊤ /dt	I ² t for fusing Repetitive rate of rise of on-state current after triggering		-		200 200		A²s A/μs
I _{GM} V _{GM} V _{RGM} P _{GM} T	Peak gate current Peak gate voltage Peak reverse gate voltage Peak gate power Average gate power	over any 20 ms period			5 5 20 0.5		A V V W W
T _{stg} T _j	Storage temperature Operating junction temperature		-40 -		150 125		°C °C

¹ Although not recommended, off-state voltages up to 800V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 A/ μ s.

BT152B series

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base		-	-	1.1	K/W
R _{th j-a}	Thermal resistance junction to ambient	minimum footprint, FR4 board	-	55	-	K/W

STATIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

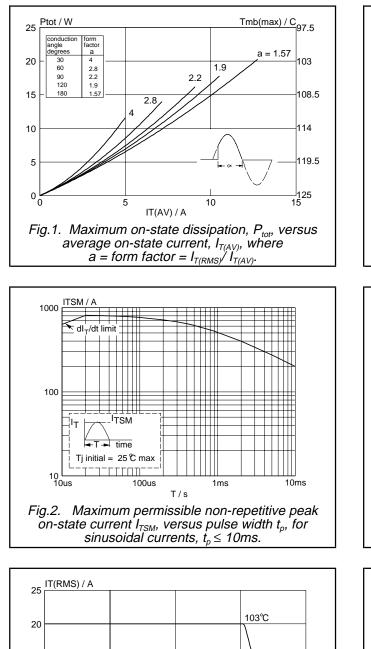
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$	-	3	32	mA
	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$	-	25	80	mA
	Holding current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$	-	15	60	mA
İ Ϋ _τ	On-state voltage	$I_{T} = 40 \text{ A}$	-	1.4	1.75	V
V _{GT}	Gate trigger voltage	$\dot{V}_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}$	-	0.6	1.5	V
		$V_{\rm D} = V_{\rm DRM(max)}; I_{\rm T} = 0.1 \text{ A}; T_{\rm i} = 125 \ ^{\circ}\text{C}$	0.25	0.4	-	V
I _D , I _R	Off-state leakage current	$V_D^{D} = V_{DRM(max)}^{DRM(max)}; V_R = V_{RRM(max)}; T_j = 125 \text{°C}$	-	0.2	1.0	mA

DYNAMIC CHARACTERISTICS

 $T_j = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform gate open circuit	200	300	-	V/µs
t _{gt}	Gate controlled turn-on	$V_{\rm D} = V_{\rm DRM(max)}$; $I_{\rm G} = 0.1$ Å; $dI_{\rm G}/dt = 5$ Å/µs; $I_{\rm TM} = 40$ Å	-	2	-	μs
t _q	Circuit commutated turn-off time	$V_{D}^{M} = 67\% V_{DRM(max)}; T_{j} = 125 °C;$ $I_{TM} = 50 A; V_{R} = 25 V; dI_{TM}/dt = 30 A/\mu s;$ $dV_{D}/dt = 50 V/\mu s; R_{GK} = 100 \Omega$	-	70	-	μs

BT152B series



50 Tmb / C

Fig.3. Maximum permissible rms current $I_{T(RMS)}$, versus mounting base temperature T_{mb} .

100

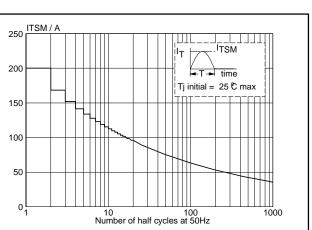


Fig.4. Maximum permissible non-repetitive peak on-state current I_{TSM} , versus number of cycles, for sinusoidal currents, f = 50 Hz.

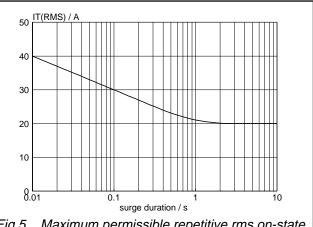
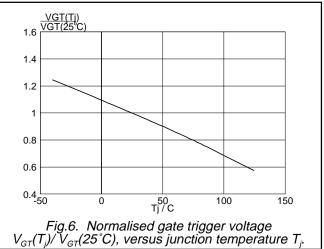


Fig.5. Maximum permissible repetitive rms on-state current $I_{T(RMS)}$, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 103$ °C.



15

10

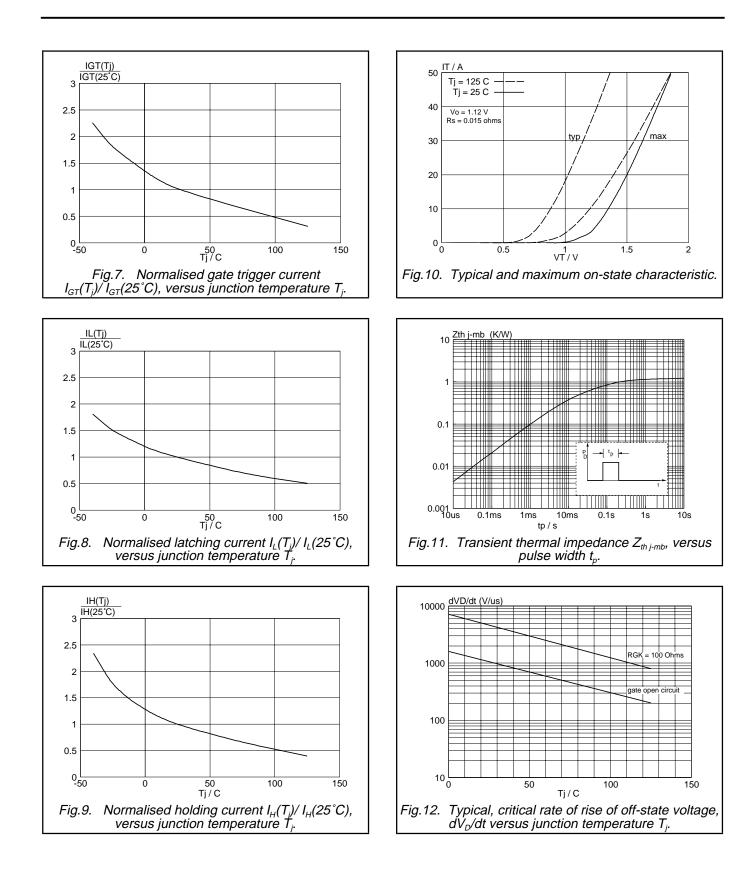
5

0 -50

0

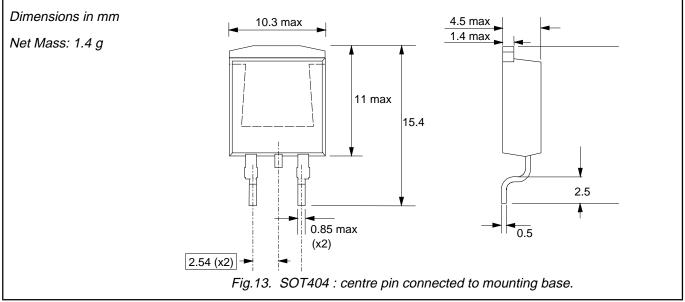
150

BT152B series



BT152B series

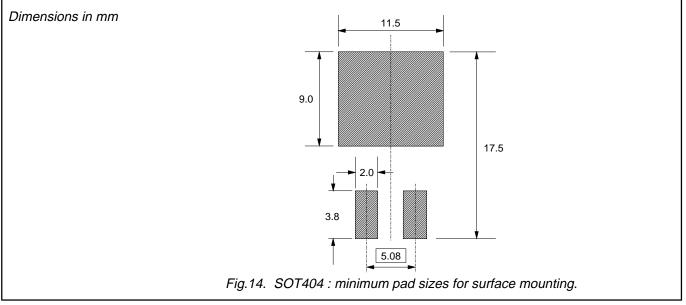
MECHANICAL DATA



Notes

1. Epoxy meets UL94 V0 at 1/8".

MOUNTING INSTRUCTIONS



Notes

1. Plastic meets UL94 V0 at 1/8".

DEFINITIONS

Data sheet status					
Objective specification	jective specification This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.					
Application information					
Where application information is given, it is advisory and does not form part of the specification.					
© Philips Electronics N.V. 1997					
All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the					

copyright owner.

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.